

AN80PxxRSP Series

5-pin, low dropout voltage regulator with standby function (1 A type)

Overview

The AN80PxxRSP series is a 1 A, low dropout voltage regulator with standby function, featuring low current consumption and low noise.

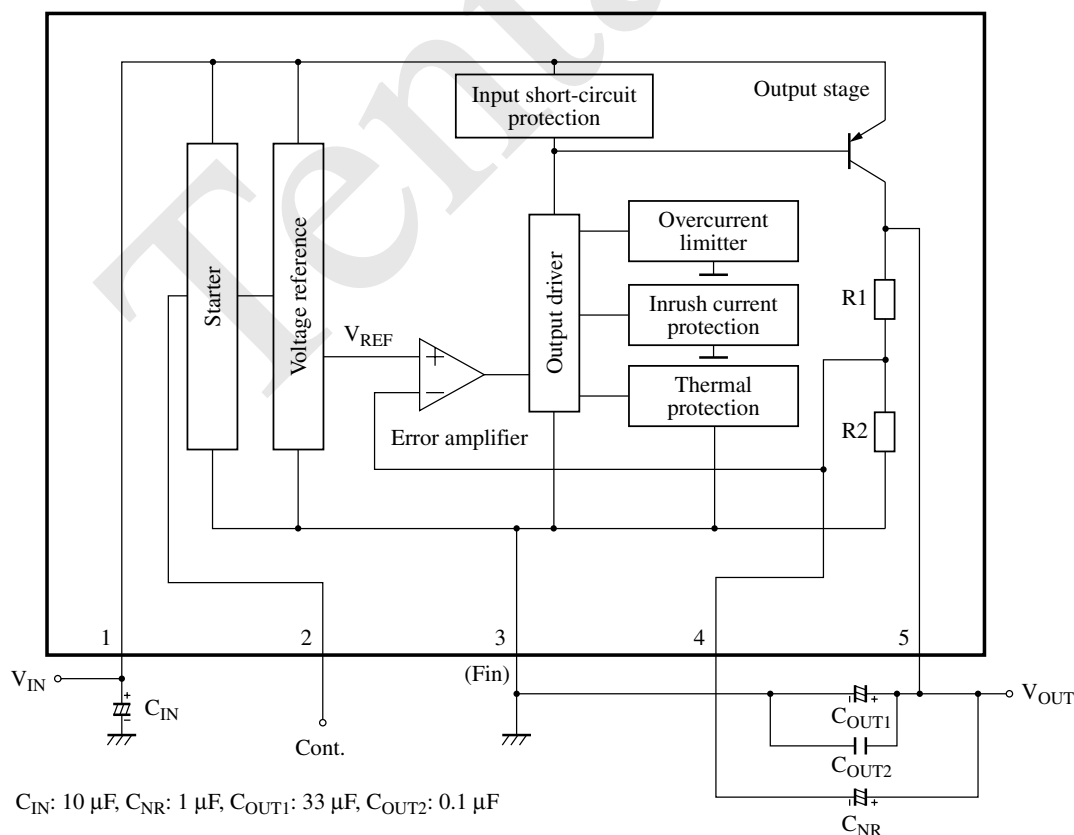
Features

- Standby consumption current: max. 3 μ A
- Dropout voltage: 0.3 V
- Output voltage accuracy: $\pm 3\%$
- 5-pin surface mounting package
- Ripple rejection ratio of 30 dB ($f = 500$ kHz)
- Output voltage: 1.8 V, 1.9 V, 2.0 V, 2.1 V, 2.2 V, 2.5 V, 2.7 V, 2.8 V, 2.9 V, 3.0 V, 3.1 V, 3.2 V, 3.3 V, 3.4 V, 3.5 V, 3.6 V, 4.8 V, 4.9 V, 5.0 V, 5.1 V, 5.2 V, 5.3 V

Applications

- General use power supply

Block Diagram



■ Pin Descriptions

Pin No.	Description
1	Input voltage pin (V_{IN})
2	Control pin (Cont.) High: operation, Low: stop
3	Grounding pin (GND) Electrically in common with radiation fin
4	Noise reduction pin (N.R.) Open when the noise reduction function is not used
5	Output voltage pin (V_{OUT})

■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V_{CC}	14.4	V
Supply current	I_{CC}	—	mA
Power dissipation ^{*1}	P_D	255	mW
Operating ambient temperature ^{*2}	T_{opr}	−30 to +85	°C
Storage temperature ^{*2}	T_{stg}	−55 to +150	°C

Note) 1. The output voltage may exceed the rated value if $T_j > 150^\circ\text{C}$ in no-load condition. Set to $I_O > 5\text{ mA}$ if T_j is likely to exceed 150°C .

2. This IC is not suitable for automobile equipment use.

3. ^{*1}: The above power dissipation shows the value of an independent IC without heat sink at $T_a = 85^\circ\text{C}$. For details, refer to "2. Power dissipation of SP-5SU package" in the Application Notes.

^{*2}: Except for the operating ambient temperature and storage temperature, all ratings are for $T_a = 25^\circ\text{C}$.

■ Recommended Operating Conditions

Part No.	Output voltage	Operating supply voltage range (V_{CC})	Unit
AN80P18RSP	1.8	2.3 to 14.0	V
AN80P19RSP	1.9	2.4 to 14.0	V
AN80P20RSP	2.0	2.5 to 14.0	V
AN80P21RSP	2.1	2.6 to 14.0	V
AN80P22RSP	2.2	2.7 to 14.0	V
AN80P25RSP	2.5	3.0 to 14.0	V
AN80P27RSP	2.7	3.2 to 14.0	V
AN80P28RSP	2.8	3.3 to 14.0	V
AN80P29RSP	2.9	3.4 to 14.0	V
AN80P30RSP	3.0	3.5 to 14.0	V
AN80P31RSP	3.1	3.6 to 14.0	V
AN80P32RSP	3.2	3.7 to 14.0	V
AN80P33RSP	3.3	3.8 to 14.0	V
AN80P34RSP	3.4	3.9 to 14.0	V
AN80P35RSP	3.5	4.0 to 14.0	V
AN80P36RSP	3.6	4.1 to 14.0	V
AN80P48RSP	4.8	5.3 to 14.0	V
AN80P49RSP	4.9	5.4 to 14.0	V
AN80P50RSP	5.0	5.5 to 14.0	V
AN80P51RSP	5.1	5.6 to 14.0	V
AN80P52RSP	5.2	5.7 to 14.0	V
AN80P53RSP	5.3	5.8 to 14.0	V

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$

• AN80P18RSP (1.8 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $CNR = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 2.8\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	1.746	1.8	1.854	V
Line regulation	REG_{IN}	$V_{IN} = 2.8\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	18	mV
Load regulation	REG_{LOA}	$V_{IN} = 2.8\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	36	mV
Peak output current	I_{PEAK}	$V_{IN} = 2.8\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 2.8\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 2.8\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 2.8\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 1.710\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 2.8\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 3.8\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	58.8	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 1.9\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 2.0\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 2.8\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 2.8\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 3.8\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $CNR = 1\ \mu\text{F}$, $V_{IN} = 2.8\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 2.8\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	ppm/ $^\circ\text{C}$
Output short-circuit current	I_{OSHORT}	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 2.8\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P19RSP (1.9 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $CNR = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 2.9\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	1.843	1.9	1.957	V
Line regulation	REG_{IN}	$V_{IN} = 2.9\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	19	mV
Load regulation	REG_{LOA}	$V_{IN} = 2.9\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	38	mV
Peak output current	I_{PEAK}	$V_{IN} = 2.9\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 2.9\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 2.9\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 2.9\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 1.805\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 2.9\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 3.9\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	58.4	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 2.0\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 2.1\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 2.9\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 2.9\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 3.9\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $CNR = 1\ \mu\text{F}$, $V_{IN} = 2.9\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 2.9\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	ppm/ $^\circ\text{C}$
Output short-circuit current	I_{OSHORT}	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 2.9\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P20RSP (2.0 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $\text{CNR} = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 3.0\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	1.940	2.0	2.060	V
Line regulation	REG_{IN}	$V_{IN} = 3.0\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	20	mV
Load regulation	REG_{LOA}	$V_{IN} = 3.0\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	40	mV
Peak output current	I_{PEAK}	$V_{IN} = 3.0\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 3.0\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 3.0\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 3.0\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 1.900\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 3.0\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 4.0\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	57.9	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 2.1\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 2.2\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 3.0\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 3.0\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 4.0\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $\text{CNR} = 1\ \mu\text{F}$, $V_{IN} = 3.0\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 3.0\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	$\text{ppm}/^\circ\text{C}$
Output short-circuit current	$I_{O\text{SHORT}}$	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{jTH}	$V_{IN} = 3.0\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P21RSP (2.1 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $CNR = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 3.1\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	2.037	2.1	2.163	V
Line regulation	REG_{IN}	$V_{IN} = 3.1\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	21	mV
Load regulation	REG_{LOA}	$V_{IN} = 3.1\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	42	mV
Peak output current	I_{PEAK}	$V_{IN} = 3.1\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 3.1\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 3.1\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 3.1\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 1.995\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 3.1\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 4.1\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	57.5	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 2.2\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 2.3\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 3.1\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 3.1\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 4.1\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $CNR = 1\ \mu\text{F}$, $V_{IN} = 3.1\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 3.1\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	ppm/ $^\circ\text{C}$
Output short-circuit current	I_{OSHORT}	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 3.1\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P22RSP (2.2 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $\text{CNR} = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 3.2\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	2.134	2.2	2.266	V
Line regulation	REG_{IN}	$V_{IN} = 3.2\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	22	mV
Load regulation	REG_{LOA}	$V_{IN} = 3.2\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	44	mV
Peak output current	I_{PEAK}	$V_{IN} = 3.2\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 3.2\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 3.2\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 3.2\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 2.090\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 3.2\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 4.2\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	57.1	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 2.3\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 2.4\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 3.2\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 3.2\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 4.2\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $\text{CNR} = 1\ \mu\text{F}$, $V_{IN} = 3.2\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 3.2\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	$\text{ppm}/^\circ\text{C}$
Output short-circuit current	$I_{O\text{SHORT}}$	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 3.2\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P25RSP (2.5 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $\text{CNR} = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 3.5\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	2.425	2.5	2.575	V
Line regulation	REG_{IN}	$V_{IN} = 3.5\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	25	mV
Load regulation	REG_{LOA}	$V_{IN} = 3.5\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mV
Peak output current	I_{PEAK}	$V_{IN} = 3.5\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 3.5\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 3.5\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 3.5\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 2.375\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 3.5\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 4.5\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	56.0	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 2.6\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 2.7\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 3.5\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 3.5\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 4.5\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $\text{CNR} = 1\ \mu\text{F}$, $V_{IN} = 3.5\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 3.5\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	$\text{ppm}/^\circ\text{C}$
Output short-circuit current	$I_{O\text{SHORT}}$	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 3.5\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P27RSP (2.7 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $CNR = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 3.7\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	2.619	2.7	2.781	V
Line regulation	REG_{IN}	$V_{IN} = 3.7\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	27	mV
Load regulation	REG_{LOA}	$V_{IN} = 3.7\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	54	mV
Peak output current	I_{PEAK}	$V_{IN} = 3.7\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 3.7\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 3.7\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 3.7\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 2.565\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 3.7\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 4.7\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	55.3	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 2.8\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 2.9\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 3.7\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 3.7\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 4.7\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $CNR = 1\ \mu\text{F}$, $V_{IN} = 3.7\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 3.7\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	ppm/ $^\circ\text{C}$
Output short-circuit current	I_{OSHORT}	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 3.7\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P28RSP (2.8 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $CNR = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 3.8\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	2.716	2.8	2.884	V
Line regulation	REG_{IN}	$V_{IN} = 3.8\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	28	mV
Load regulation	REG_{LOA}	$V_{IN} = 3.8\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	56	mV
Peak output current	I_{PEAK}	$V_{IN} = 3.8\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 3.8\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 3.8\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 3.8\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 2.660\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 3.8\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 4.8\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	55.0	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 2.9\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 3.0\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 3.8\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 3.8\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 4.8\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $CNR = 1\ \mu\text{F}$, $V_{IN} = 3.8\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 3.8\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	ppm/ $^\circ\text{C}$
Output short-circuit current	I_{OSHORT}	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 3.8\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P29RSP (2.9 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $\text{CNR} = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 3.9\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	2.813	2.9	2.987	V
Line regulation	REG_{IN}	$V_{IN} = 3.9\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	29	mV
Load regulation	REG_{LOA}	$V_{IN} = 3.9\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	58	mV
Peak output current	I_{PEAK}	$V_{IN} = 3.9\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 3.9\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 3.9\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 3.9\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 2.755\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 3.9\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 4.9\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	54.7	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 3.0\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 3.1\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 3.9\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 3.9\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 4.9\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $\text{CNR} = 1\ \mu\text{F}$, $V_{IN} = 3.9\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 3.9\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	$\text{ppm}/^\circ\text{C}$
Output short-circuit current	I_{OSHORT}	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 3.9\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P30RSP (3.0 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $CNR = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 4.0\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	2.910	3.0	3.090	V
Line regulation	REG_{IN}	$V_{IN} = 4.0\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	30	mV
Load regulation	REG_{LOA}	$V_{IN} = 4.0\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	60	mV
Peak output current	I_{PEAK}	$V_{IN} = 4.0\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 4.0\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 4.0\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 4.0\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 2.850\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 4.0\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 5.0\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	54.1	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 3.1\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 3.2\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 4.0\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 4.0\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 5.0\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $CNR = 1\ \mu\text{F}$, $V_{IN} = 4.0\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 4.0\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	ppm/ $^\circ\text{C}$
Output short-circuit current	I_{OSHORT}	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 4.0\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P31RSP (3.1 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $\text{CNR} = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 4.1\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	3.007	3.1	3.193	V
Line regulation	REG_{IN}	$V_{IN} = 4.1\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	31	mV
Load regulation	REG_{LOA}	$V_{IN} = 4.1\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	62	mV
Peak output current	I_{PEAK}	$V_{IN} = 4.1\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 4.1\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 4.1\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 4.1\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 2.945\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 4.1\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 5.1\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	54.1	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 3.2\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 3.3\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 4.1\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 4.1\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 5.1\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $\text{CNR} = 1\ \mu\text{F}$, $V_{IN} = 4.1\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 4.1\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	$\text{ppm}/^\circ\text{C}$
Output short-circuit current	$I_{O\text{SHORT}}$	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 4.1\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P32RSP (3.2 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $C_{NR} = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 4.2\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	3.104	3.2	3.296	V
Line regulation	REG_{IN}	$V_{IN} = 4.2\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	32	mV
Load regulation	REG_{LOA}	$V_{IN} = 4.2\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	64	mV
Peak output current	I_{PEAK}	$V_{IN} = 4.2\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 4.2\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 4.2\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 4.2\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 3.040\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 4.2\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 5.2\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	53.8	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 3.3\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 3.4\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 4.2\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 4.2\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 5.2\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $C_{NR} = 1\ \mu\text{F}$, $V_{IN} = 4.2\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 4.2\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	$\text{ppm}/^\circ\text{C}$
Output short-circuit current	$I_{O\text{SHORT}}$	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 4.2\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P33RSP (3.3 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $CNR = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 4.3\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	3.201	3.3	3.399	V
Line regulation	REG_{IN}	$V_{IN} = 4.3\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	33	mV
Load regulation	REG_{LOA}	$V_{IN} = 4.3\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	66	mV
Peak output current	I_{PEAK}	$V_{IN} = 4.3\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 4.3\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 4.3\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 4.3\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 3.135\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 4.3\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 5.3\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	53.6	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 3.4\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 3.5\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 4.3\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 4.3\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 5.3\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $CNR = 1\ \mu\text{F}$, $V_{IN} = 4.3\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 4.3\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	ppm/ $^\circ\text{C}$
Output short-circuit current	I_{OSHORT}	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 4.3\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P34RSP (3.4 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $CNR = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 4.4\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	3.298	3.4	3.502	V
Line regulation	REG_{IN}	$V_{IN} = 4.4\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	34	mV
Load regulation	REG_{LOA}	$V_{IN} = 4.4\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	68	mV
Peak output current	I_{PEAK}	$V_{IN} = 4.4\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 4.4\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 4.4\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 4.4\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 3.230\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 4.4\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 5.4\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	53.3	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 3.5\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 3.6\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 4.4\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 4.4\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 5.4\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $CNR = 1\ \mu\text{F}$, $V_{IN} = 4.4\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 4.4\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	ppm/ $^\circ\text{C}$
Output short-circuit current	$I_{O\text{SHORT}}$	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 4.4\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P35RSP (3.5 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $\text{CNR} = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 4.5\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	3.395	3.5	3.605	V
Line regulation	REG_{IN}	$V_{IN} = 4.5\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	35	mV
Load regulation	REG_{LOA}	$V_{IN} = 4.5\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	70	mV
Peak output current	I_{PEAK}	$V_{IN} = 4.5\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 4.5\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 4.5\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 4.5\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 3.325\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 4.5\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 5.5\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	53.1	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 3.6\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 3.7\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 4.5\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 4.5\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 5.5\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $\text{CNR} = 1\ \mu\text{F}$, $V_{IN} = 4.5\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 4.5\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	$\text{ppm}/^\circ\text{C}$
Output short-circuit current	$I_{O\text{SHORT}}$	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 4.5\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P36RSP (3.6 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $CNR = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 4.6\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	3.492	3.6	3.708	V
Line regulation	REG_{IN}	$V_{IN} = 4.6\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	36	mV
Load regulation	REG_{LOA}	$V_{IN} = 4.6\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	72	mV
Peak output current	I_{PEAK}	$V_{IN} = 4.6\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 4.6\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 4.6\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 4.6\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 3.420\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 4.6\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 5.6\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	52.8	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 3.7\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 3.8\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 4.6\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 4.6\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 5.6\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $CNR = 1\ \mu\text{F}$, $V_{IN} = 4.6\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 4.6\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	ppm/ $^\circ\text{C}$
Output short-circuit current	I_{OSHORT}	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 4.6\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P48RSP (4.8 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $\text{CNR} = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 5.8\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	4.656	4.8	4.944	V
Line regulation	REG_{IN}	$V_{IN} = 5.8\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	48	mV
Load regulation	REG_{LOA}	$V_{IN} = 5.8\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	96	mV
Peak output current	I_{PEAK}	$V_{IN} = 5.8\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 5.8\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 5.8\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 5.8\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 4.560\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 5.8\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 6.8\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	50.3	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 4.9\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 5.0\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 5.8\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 5.8\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 6.8\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $\text{CNR} = 1\ \mu\text{F}$, $V_{IN} = 5.8\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 5.8\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	$\text{ppm}/^\circ\text{C}$
Output short-circuit current	I_{OSHORT}	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 5.8\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P49RSP (4.9 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $CNR = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 5.9\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	4.753	4.9	5.047	V
Line regulation	REG_{IN}	$V_{IN} = 5.9\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	49	mV
Load regulation	REG_{LOA}	$V_{IN} = 5.9\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	98	mV
Peak output current	I_{PEAK}	$V_{IN} = 5.9\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 5.9\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 5.9\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 5.9\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 4.655\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 5.9\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 6.9\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	50.1	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 5.0\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 5.1\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 5.9\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 5.9\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 6.9\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $CNR = 1\ \mu\text{F}$, $V_{IN} = 5.9\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 5.9\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	ppm/ $^\circ\text{C}$
Output short-circuit current	I_{OSHORT}	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 5.9\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P50RSP (5.0 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $CNR = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 6.0\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	4.850	5.0	5.150	V
Line regulation	REG_{IN}	$V_{IN} = 6.0\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	60	mV
Load regulation	REG_{LOA}	$V_{IN} = 6.0\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	120	mV
Peak output current	I_{PEAK}	$V_{IN} = 6.0\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 6.0\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 6.0\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 6.0\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 4.750\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 6.0\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 7.0\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	49.9	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 5.1\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 5.2\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 6.0\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 6.0\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 7.0\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $CNR = 1\ \mu\text{F}$, $V_{IN} = 6.0\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 6.0\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	$\text{ppm}/^\circ\text{C}$
Output short-circuit current	$I_{O\text{SHORT}}$	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 6.0\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P51RSP (5.1 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $CNR = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 6.1\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	4.947	5.1	5.253	V
Line regulation	REG_{IN}	$V_{IN} = 6.1\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	51	mV
Load regulation	REG_{LOA}	$V_{IN} = 6.1\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	102	mV
Peak output current	I_{PEAK}	$V_{IN} = 6.1\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 6.1\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 6.1\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 6.1\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 4.845\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 6.1\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 7.1\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	49.8	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 5.2\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 5.3\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 6.1\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 6.1\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 7.1\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $CNR = 1\ \mu\text{F}$, $V_{IN} = 6.1\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 6.1\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	ppm/ $^\circ\text{C}$
Output short-circuit current	I_{OSHORT}	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 6.1\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P52RSP (5.2 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $CNR = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 6.2\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	5.044	5.2	5.356	V
Line regulation	REG_{IN}	$V_{IN} = 6.2\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	52	mV
Load regulation	REG_{LOA}	$V_{IN} = 6.2\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	104	mV
Peak output current	I_{PEAK}	$V_{IN} = 6.2\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 6.2\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 6.2\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 6.2\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 4.940\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 6.2\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 7.2\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	49.6	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 5.3\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 5.4\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 6.2\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 6.2\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 7.2\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $CNR = 1\ \mu\text{F}$, $V_{IN} = 6.2\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 6.2\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	ppm/ $^\circ\text{C}$
Output short-circuit current	$I_{O\text{SHORT}}$	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 6.2\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN80P53RSP (5.3 V type)

Unless otherwise specially provided, shorten each test time (within 10 ms) so that the test is conducted under the condition that the drift due to the temperature increase in the chip junction part can be neglected. $C_{IN} = 10\ \mu\text{F}$, $CNR = \text{Open}$, $C_{OUT} = 33\ \mu\text{F}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_{OUT}	$V_{IN} = 6.3\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	5.141	5.3	5.459	V
Line regulation	REG_{IN}	$V_{IN} = 6.3\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	—	—	53	mV
Load regulation	REG_{LOA}	$V_{IN} = 6.3\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	106	mV
Peak output current	I_{PEAK}	$V_{IN} = 6.3\ \text{V}$, The output current value when V_{OUT} decreases by 5% from its value at $I_{OUT} = 500\ \text{mA}$.	1200	—	—	mA
Bias current under no load	I_{BIAS}	$V_{IN} = 6.3\ \text{V}$, $I_{OUT} = 0\ \text{mA}$	—	1.1	3.0	mA
Bias current fluctuation to input	$\Delta I_{BIAS(IN)}$	$V_{IN} = 6.3\ \text{V} \rightarrow 14.0\ \text{V}$, $I_{OUT} = 250\ \text{mA}$	-5	—	5	mA
Bias current fluctuation to load	$\Delta I_{BIAS(LOA)}$	$V_{IN} = 6.3\ \text{V}$, $I_{OUT} = 0\ \text{mA} \rightarrow 1000\ \text{mA}$	—	—	50	mA
Standby consumption current	I_{STB}	$V_{IN} = 14.0\ \text{V}$, $V_{CONT} = 0\ \text{V}$	—	—	3.0	μA
Bias current before starting regulation	I_{RUSH}	$V_{IN} = 5.035\ \text{V}$, $I_{OUT} = 0\ \text{A}$	—	—	5	mA
Control terminal current	I_{CONT}	$V_{IN} = 6.3\ \text{V}$, $I_{OUT} = 500\ \text{mA}$ $V_{CONT} = 1.8\ \text{V}$	—	—	30	μA
Ripple rejection ratio 1	RR1	$V_{IN} = 7.3\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 120\ \text{Hz}$, $I_{OUT} = 100\ \text{mA}$	49.5	—	—	dB
Minimum input/output voltage difference 1	$V_{DIF(min)1}$	$V_{IN} = 5.4\ \text{V}$, $I_{OUT} = 500\ \text{mA}$	—	0.30	0.60	V
Minimum input/output voltage difference 2	$V_{DIF(min)2}$	$V_{IN} = 5.5\ \text{V}$, $I_{OUT} = 1000\ \text{mA}$	—	—	1.0	V
Control terminal threshold high voltage	V_{CONTH}	$V_{IN} = 6.3\ \text{V}$	—	1.45	1.80	V
Control terminal threshold low voltage	V_{CONTL}	$V_{IN} = 6.3\ \text{V}$	0.50	0.70	—	V

• Design reference data

Note) The following values are typical and not guaranteed values.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple rejection ratio 2	RR2	$V_{IN} = 7.3\ \text{V} \pm 1\ \text{V[p-p]}$ $f = 500\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$	—	30	—	dB
Output noise voltage	V_{NO}	$10\ \text{Hz} \leq f \leq 100\ \text{kHz}$, $I_{OUT} = 100\ \text{mA}$ $CNR = 1\ \mu\text{F}$, $V_{IN} = 6.3\ \text{V}$	—	40	—	$\mu\text{V[rms]}$
Output voltage temperature coefficient	$\frac{dV_{OUT}}{dT_a}$	$V_{IN} = 6.3\ \text{V}$, $I_{OUT} = 5\ \text{mA}$ $-30^\circ\text{C} \leq T_a \leq +125^\circ\text{C}$	—	± 40	—	ppm/ $^\circ\text{C}$
Output short-circuit current	I_{OSHORT}	$V_{IN} = 14.0\ \text{V}$, $V_{OUT} = \text{GND}$	—	600	—	mA
Overheat protection operating temperature	T_{JTH}	$V_{IN} = 6.3\ \text{V}$, $I_{OUT} = 5\ \text{mA}$	—	150	—	$^\circ\text{C}$

■ Application Notes

1. External compensation capacitor

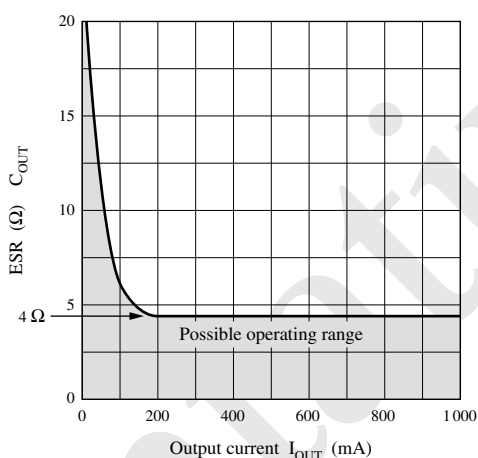
Connect the input pin and ground pin with a 10 μF capacitor and the output pin and ground pin with a 33 μF capacitor in order to keep the stability of the IC in operation. Make sure that the 10 μF capacitor is as close to the input pin and ground pin as possible while the 33 μF capacitor is as close to the output pin and ground pin as possible.

As the stability is affected by the parasitic capacitance and impedance of the PCB pattern, pay utmost attention to the PCB layout.

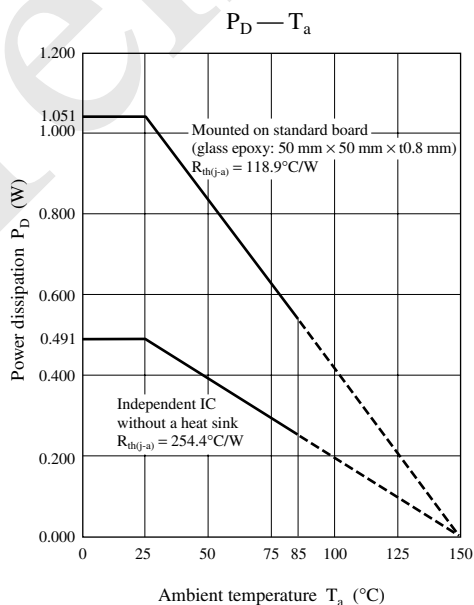
Select each capacitor in consideration of the ESR (equivalent series resistance) of the capacitor for the AN80PxxRSP Series, conduct a full evaluation under the right operating conditions.

The ESR of an aluminum or tantalum electrolytic capacitor may increase at low temperatures. Therefore, it is recommended to connect a 0.1 μF to 0.47 μF capacitor with low internal impedance, such as a multi-layer ceramic capacitor, in parallel to each capacitor.

Output current — Output capacitor ESR (equivalent series resistance)



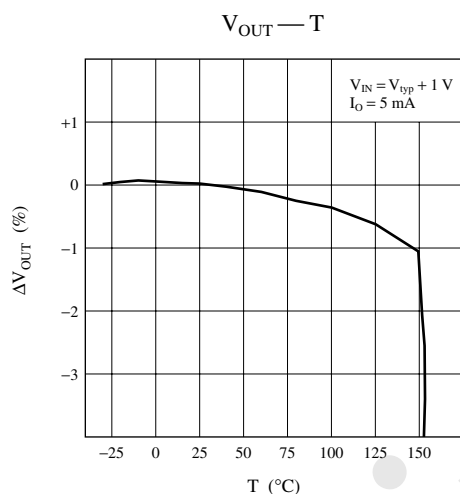
2. $P_D - T_a$ curves of SP-5SU



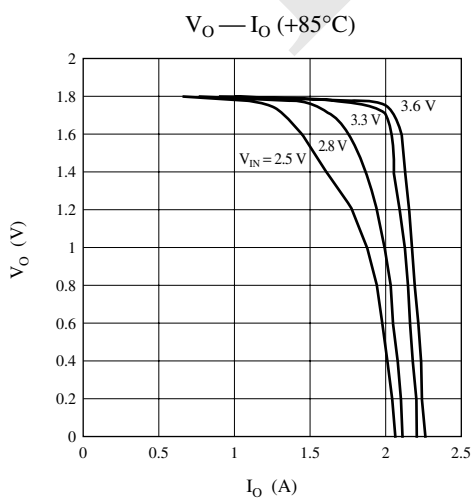
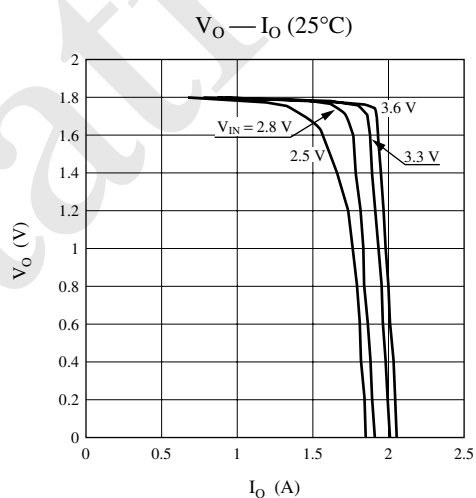
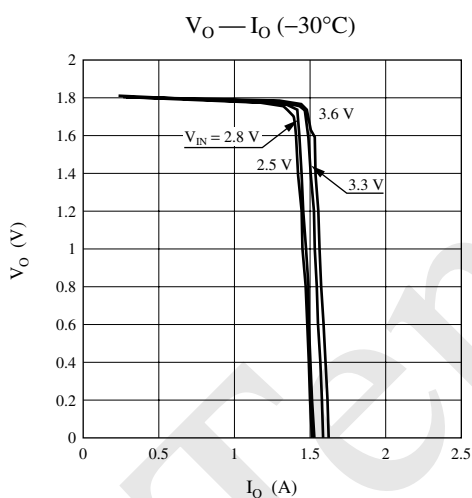
■ Application Notes (continued)

3. Main characteristics

- AN80PxxRSP series



- AN80P18RSP



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